## NSN 5961-01-021-2407

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View Online at https://aerobasegroup.com/nsn/5961-01-021-2407 **Inclosure Material:** Metal **Overall Length:** Between 0.165 inches and 0.185 inches **Terminal Length:** 0.500 inches **Overall Diameter:** Between 0.335 inches and 0.370 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-99 **Component Name And Quantity:** 2 transistor **Mounting Method: Terminal Features Provided:** Electrostatic sensitive and hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: -40.0 drain to gate voltage all transistor and 40.0 gate to source voltage all transistor **Current Rating Per Characteristic:** 50.00 milliamperes drain current all transistor **Power Rating Per Characteristic:** 525.0 milliwatts total device dissipation all transistor **Terminal Type And Quantity:** 8 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli